## NSN 5961-01-265-2162

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-265-2162 **Inclosure Material:** Metal **Overall Length:** 0.902 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.206 inches **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 3.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 500.00 microamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 1.0 watts large-signal input power, common-emitter preset **Transfer Ratio:** 10.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:** 

Fiig:

No

**Demilitarization:** 

A110a0